

High Voltage 3-Phase Motor Driver

Features and Benefits

- Built-in pre-drive IC
- CMOS compatible input (5 V)
- High-side gate driver using bootstrap circuit or floating power supply
- Built-in protection circuit for controlling power supply voltage drop
- Built-in overheat detection circuit (TD)
- Output of fault signal during operation of protection circuit
- Output current 2.5 A
- Small SIP (SMA 24-pin)

Description

The SMA6843MP inverter power module (IPM) device provides a robust, highly-integrated solution for optimally controlling 3-phase motor power inverter systems and variable speed control systems used in energy-conserving designs to drive motors of residential and commercial appliances. These ICs take 230 VAC input voltage, and 2.5 A (continuous) output current. They can withstand voltages of up to 500 V (MOSFET breakdown voltage).

The SMA6840MP power package includes an IC with all of the necessary power elements (six MOSFETs) and pre-driver ICs (two) needed to configure the main circuit of an inverter. This enables the main circuit of the inverter to be configured with fewer external components than traditional designs.

Applications include residential white goods (home applications) and commercial appliance motor control:

- Air conditioner fan
- Refrigerator compressor
- Dishwasher pump

Packages: Power SIP



Leadform 2451



Leadform 2452

Not to scale

Functional Block Diagram

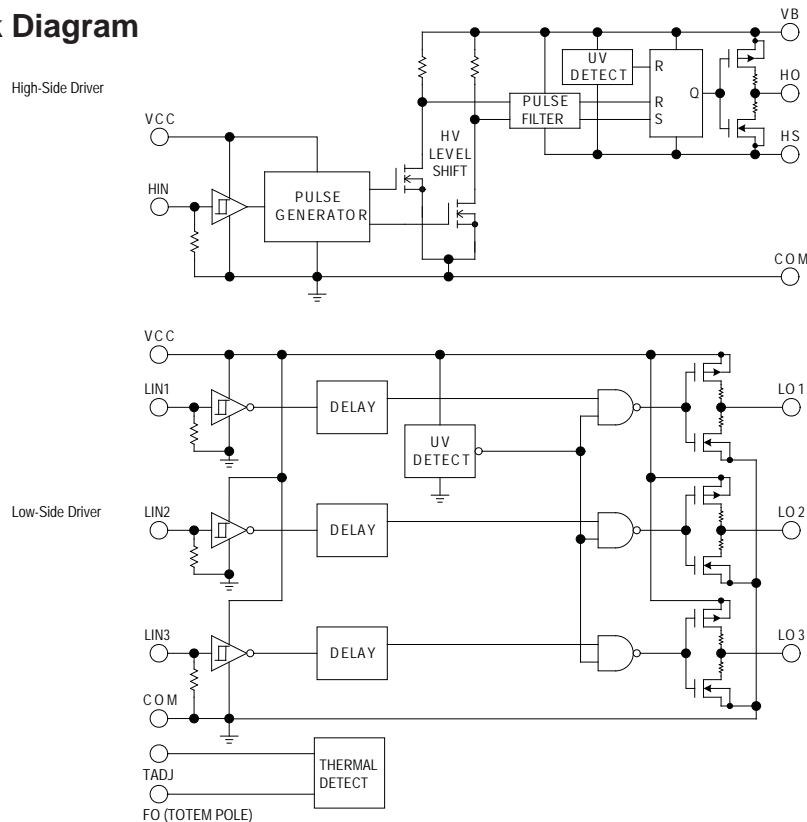


Figure 1. Driver block diagrams.

Selection Guide

Part Number	Packing	MOSFET Breakdown Voltage, $V_{DSS(min)}$ (V)	Output Current	
			Continuous, $I_O(max)$ (A)	Pulsed, $I_{OP}(max)$ (A)
SMA6843MP	18 pieces per tube	500	2.5	5

Absolute Maximum Ratings, valid at $T_A = 25^\circ\text{C}$

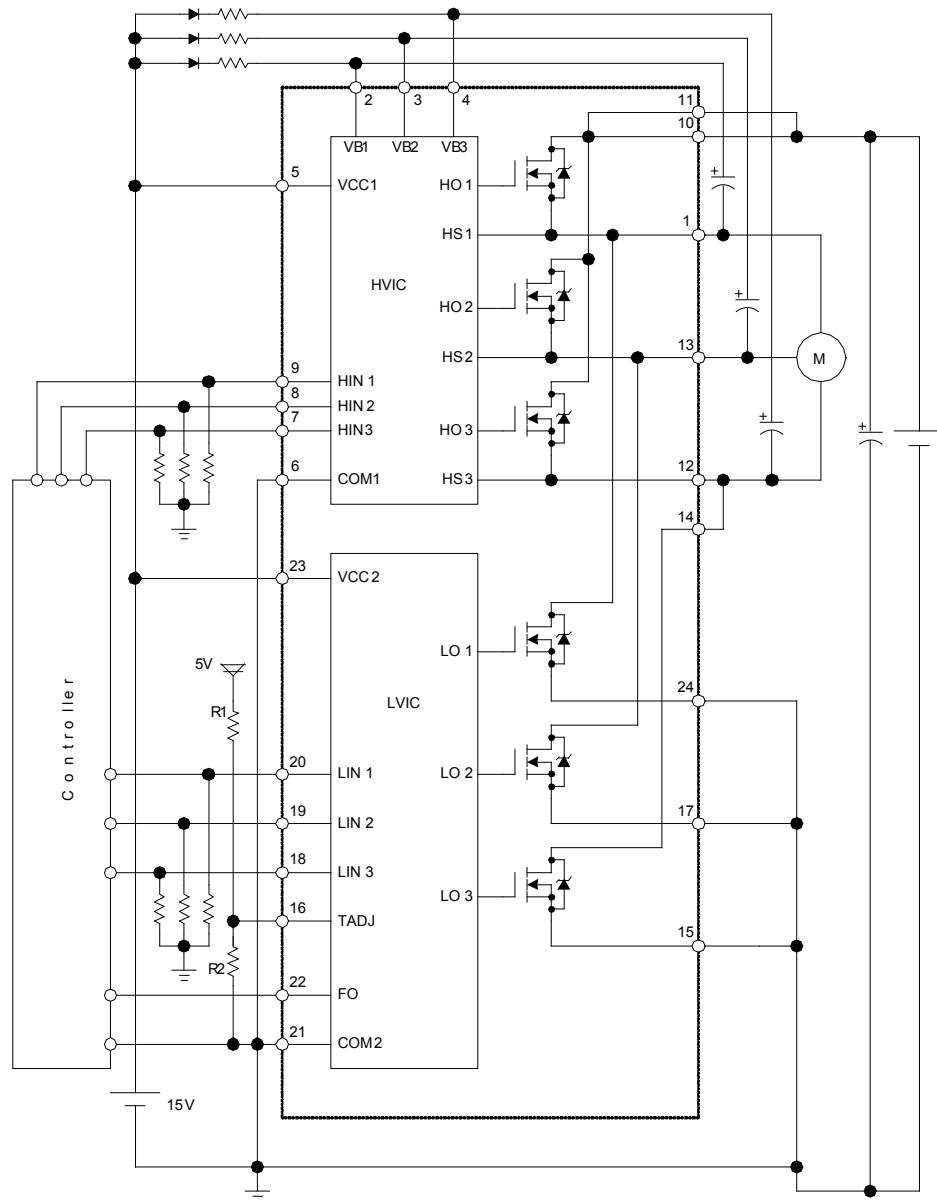
Characteristic	Symbol	Remarks	Rating	Unit
MOSFET Breakdown Voltage	V_{DSS}	$V_{CC} = 15\text{ V}$, $I_D = 100\ \mu\text{A}$, $V_{IN} = 0\text{ V}$	500	V
Logic Supply Voltage	V_{CC}	Between VCC and COM	20	V
Bootstrap Voltage	V_{BS}	Between VB and HS (U,V, and W phases)	20	V
Output Current, Continuous	I_O	$T_C = 25^\circ\text{C}$	2.5	A
Output Current, Pulsed	I_{OP}	$PW \leq 100\ \mu\text{s}$, duty cycle = 1%	5	A
Input Voltage	V_{IN}		-0.5 to 7	V
TADJ Terminal Voltage	V_{TADJ}	Between TADJ and COM	7	V
Allowable Power Dissipation	P_D	$T_C = 25^\circ\text{C}$	28	W
Thermal Resistance (Junction to Case)	$R_{\theta JC}$	All elements operating	4.46	$^\circ\text{C/W}$
Thermal Resistance (Junction to Ambient)	$R_{\theta JA}$	All elements operating	31.25	$^\circ\text{C/W}$
Case Operating Temperature	T_{COP}		-20 to 100	$^\circ\text{C}$
Junction Temperature (IGBT)	T_J		150	$^\circ\text{C}$
Storage Temperature	T_{stg}		-40 to 150	$^\circ\text{C}$

Recommended Operating Conditions

Characteristic	Symbol	Remarks	Min.	Typ.	Max.	Units
Main Supply Voltage	V_{BB}	Between VBB and LS	-	280	400	V
Logic Supply Voltage	V_{CC}	Between VCC and COM	13.5	-	16.5	V
Dead Time	t_{dead}		1.5	-	-	μs
Junction Temperature	T_J		-	-	125	$^\circ\text{C}$

All performance characteristics given are typical values for circuit or system baseline design only and are at the nominal operating voltage and an ambient temperature, T_A , of 25°C , unless otherwise stated.

Typical Application Diagram



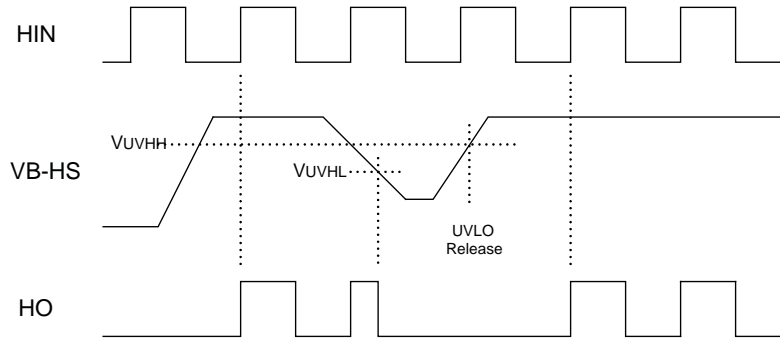
NOTE:

- All of the input pins are connected to GND with internal pull-down resistors rated at 100 kΩ, however, an external pull-down resistor may be required to secure stable condition of the inputs if high impedance conditions are applied to them.
- The external electrolytic capacitors should be placed as close to the IC as possible, in order to avoid malfunctions from external noise interference. Put a ceramic capacitor in parallel with the electrolytic capacitor if further reduction of noise susceptibility is necessary.

ELECTRICAL CHARACTERISTICS, valid at $T_A=25^{\circ}\text{C}$, unless otherwise noted

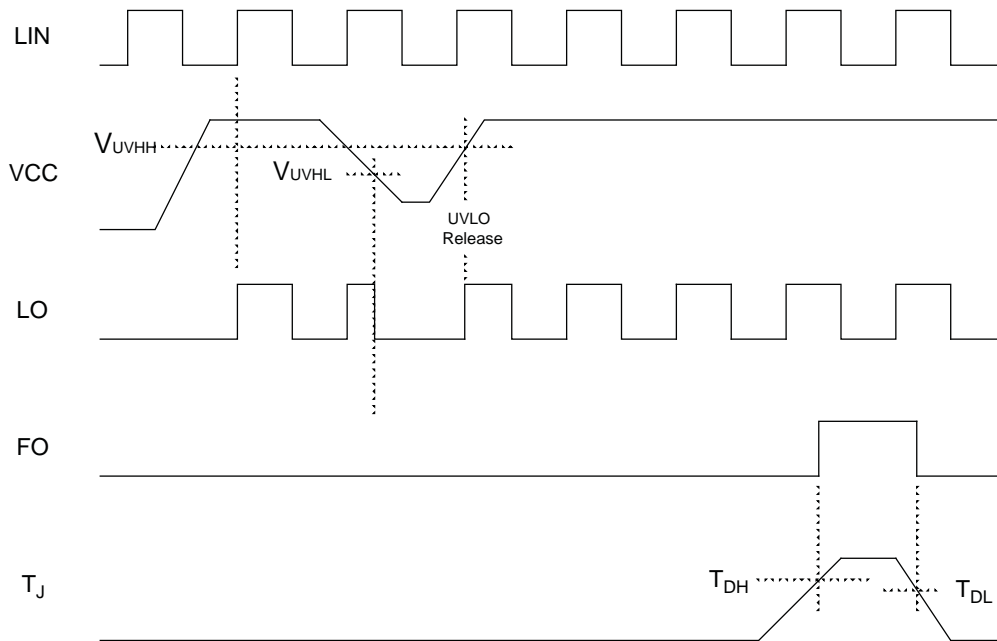
Characteristics	Symbol	Conditions	Min	Typ	Max	Units
Logic Supply Voltage	V_{CC}	Between VCC and COM	13.5	15	16.5	V
Logic Supply Current	I_{CC}	$V_{CC} = 15\text{ V}$, $I_{REG} = 0\text{ A}$	–	4	6	mA
Input Voltage	V_{IH}	$V_{CC} = 15\text{ V}$, output on	–	2.0	2.5	V
	V_{IL}	$V_{CC} = 15\text{ V}$, output off	1.0	1.5	–	V
Input Voltage Hysteresis	V_{Ihys}	$V_{CC} = 15\text{ V}$	–	0.5	–	V
Input Current	I_{IH}	High side, $V_{CC} = 15\text{ V}$, $V_{IN} = 5\text{ V}$	–	50	100	μA
	I_{IL}	Low side, $V_{CC} = 15\text{ V}$, $V_{IN} = 0\text{ V}$	–	–	2	μA
Undervoltage Lock Out	V_{UVHL}	High side, between VB and U, V, or W	9.0	10.0	11.0	V
	V_{UVHH}		9.5	10.5	11.5	V
	V_{UVHhys}	High side, hysteresis	–	0.5	–	V
	V_{UVLL}	Low side, between VB and U, V, or W	10.0	11.0	12.0	V
	V_{UVLH}		10.5	11.5	12.5	V
	V_{UVLhys}	Low side, hysteresis	–	0.5	–	V
FO Terminal Output Voltage	V_{FOL}	$V_{CC} = 15\text{ V}$, $I_{FO} = \pm 1\text{ mA}$	0	–	0.8	V
	V_{FOH}		4.5	–	5.5	V
Overtemperature Detection Activation Threshold Temperature	$T_{DH(1)}$	$V_{CC} = 15\text{ V}$, no heatsink, TADJ terminal open	134	150	160	$^{\circ}\text{C}$
	$T_{DH(2)}$	$V_{CC} = 15\text{ V}$, no heatsink, $R_1 = 240\text{ k}\Omega$; no R2	112	131	148	$^{\circ}\text{C}$
Overtemperature Detection Deactivation Threshold Temperature	$T_{DL(1)}$	$V_{CC} = 15\text{ V}$, no heatsink, TADJ terminal open	104	120	135	$^{\circ}\text{C}$
	$T_{DL(2)}$	$V_{CC} = 15\text{ V}$, no heatsink, $R_1 = 240\text{ k}\Omega$; no R2	80	99	120	$^{\circ}\text{C}$
MOSFET Breakdown Voltage	V_{DSS}	$V_{CC} = 15\text{ V}$, $I_D = 100\text{ }\mu\text{A}$, $V_{IN} = 0\text{ V}$	500	–	–	V
MOSFET Leakage Current	I_{DSS}	$V_{CC} = 15\text{ V}$, $V_{DS} = 500\text{ V}$, $V_{IN} = 0\text{ V}$	–	–	100	μA
MOSFET On State Resistance	$R_{DS(on)}$	$V_{CC} = 15\text{ V}$, $I_D = 1.5\text{ A}$, $V_{IN} = 5\text{ V}$	–	2.0	2.4	Ω
MOSFET Diode Forward Voltage	V_{SD}	$V_{CC} = 15\text{ V}$, $I_{SD} = 1.5\text{ A}$, $V_{IN} = 0\text{ V}$	–	1	1.5	V
MOSFET Diode Recovery Time	t_{rr}	$I_{SD} = 1.5\text{ A}$, $di/dt = 100\text{ A}/\mu\text{s}$	–	75	–	ns
Switching Time, High Side	$t_{dH(on)}$	$V_{BB} = 300\text{ V}$, $V_{CC} = 15\text{ V}$, $I_D = 2.5\text{ A}$, $0\text{ V} \leq V_{IN} \leq 5\text{ V}$	–	450	–	ns
	t_{rH}		–	60	–	ns
	$t_{dH(off)}$		–	340	–	ns
	t_{fH}		–	30	–	ns
Switching Time, Low Side	$t_{dL(on)}$		–	480	–	ns
	t_{rL}		–	70	–	ns
	$t_{dL(off)}$		–	400	–	ns
	t_{fL}		–	30	–	ns

High Side Driver Input/Output Timing Diagrams



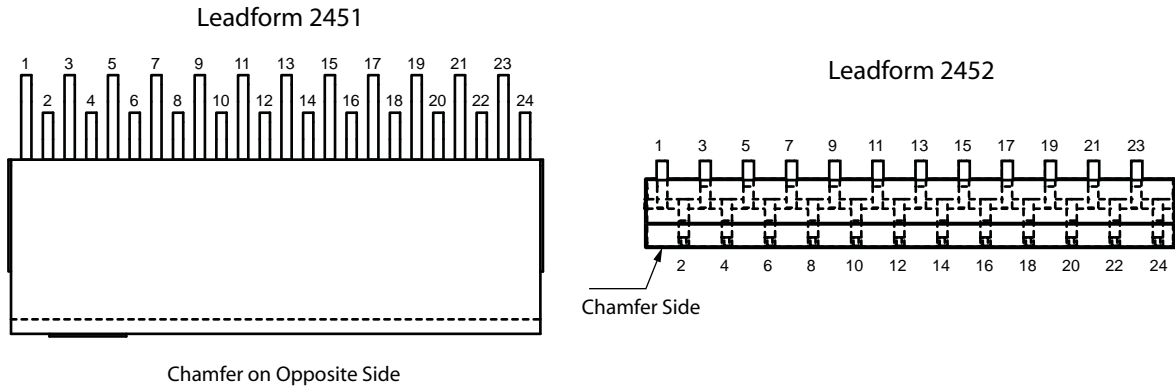
After UVLO is released, IC operation is started by the first rising edge of input

Low Side Driver Input/Output Timing Diagrams



After UVLO is released, IC operation is started by the first rising edge of input

Pin-out Diagrams

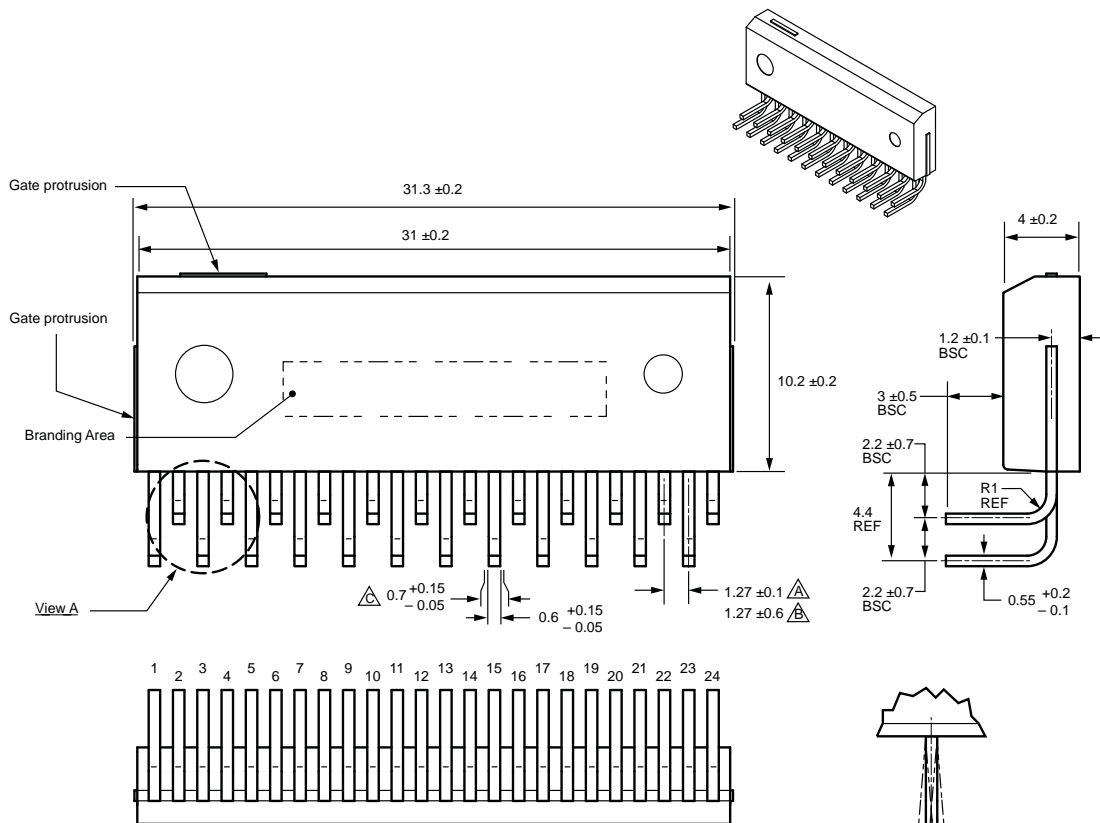


Terminal List Table

Number	Name	Function
1	U	Output of U phase
2	VB1	High side bootstrap terminal (U phase)
3	VB2	High side bootstrap terminal (V phase)
4	VB3	High side bootstrap terminal (W phase)
5	VCC1	High side logic supply voltage
6	COM1	High side logic GND terminal
7	HIN3	High side input terminal (W phase)
8	HIN2	High side input terminal (V phase)
9	HIN1	High side input terminal (U phase)
10	VBB1	Main supply voltage 1 (connect to VBB2 externally)
11	VBB2	Main supply voltage 2 (connect to VBB1 externally)
12	W1	Output of W phase (connect to W2 externally)
13	V	Output of V phase
14	W2	Output of W phase (connect to W1 externally)
15	LS3	Low side source terminal (W phase)
16	TADJ	Overtemperature detection activation temperature adjustment terminal
17	LS2	Low side source terminal (V phase)
18	LIN3	Low side input terminal (W phase)
19	LIN2	Low side input terminal (V phase)
20	LIN1	Low side input terminal (U phase)
21	COM2	Low side GND terminal
22	FO	Overcurrent protection fault-signal output terminal
23	VCC2	Low side logic supply voltage
24	LS1	Low side source terminal (U phase)

Package Outline Drawing Leadform 2451

Dual rows, 24 alternating pins; pins bent 90° for horizontal case mounting; pin #1 in outer row



- △ Measured at pin exit from case
- △ Measured at pin tips
- △ Maximum dambar protrusion

Leadform: 2451
Terminal core material: Cu
Terminal plating: Ni
Recommended attachment: Solder dip (Sn-Ag-Cu)

Dimensions in millimeters

Branding codes (exact appearance at manufacturer discretion):

1st line, lot: **YMDDT**

Where: Y is the last digit of the year of manufacture

M is the month (1 to 9, O, N, D)

DD is the date

T is the tracking letter

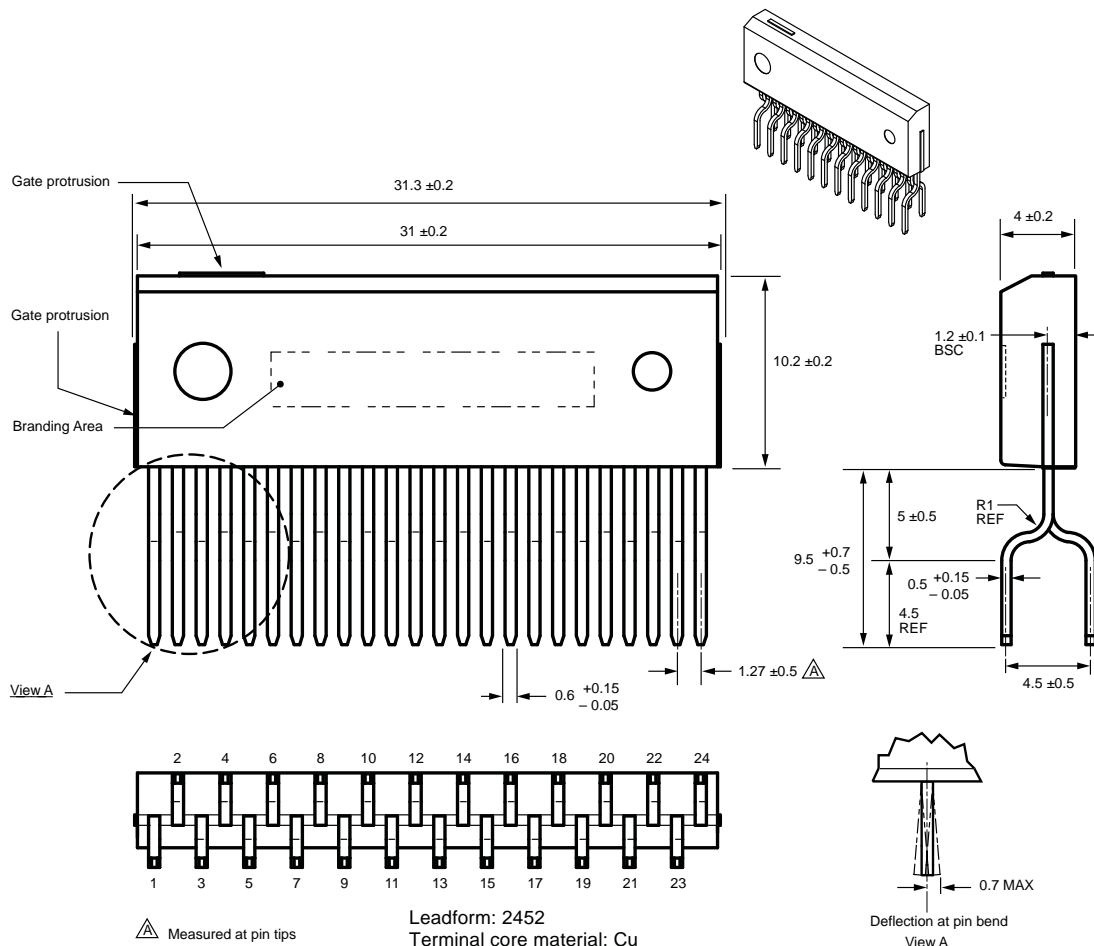
2nd line, type: SMA6843MP



Leadframe plating Pb-free. Device composition complies with the RoHS directive.

Package Outline Drawing Leadform 2452

Dual rows, 24 alternating pins; vertical case mounting; pin #1 opposite chamfer side



△ Measured at pin tips

Leadform: 2452
Terminal core material: Cu
Terminal plating: Ni
Recommended attachment: Solder dip (Sn-Ag-Cu)

Dimensions in millimeters

Branding codes (exact appearance at manufacturer discretion):

1st line, lot: YMDDT

Where: Y is the last digit of the year of manufacture

M is the month (1 to 9, O, N, D)

DD is the date

T is the tracking letter

2nd line, type: SMA6843MP

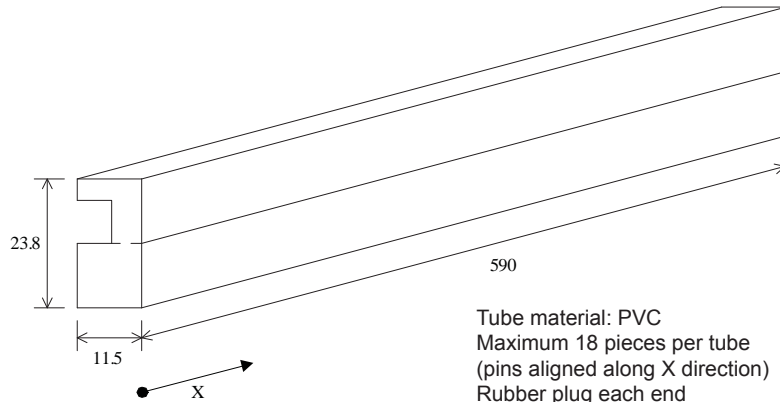


Leadframe plating Pb-free. Device composition complies with the RoHS directive.

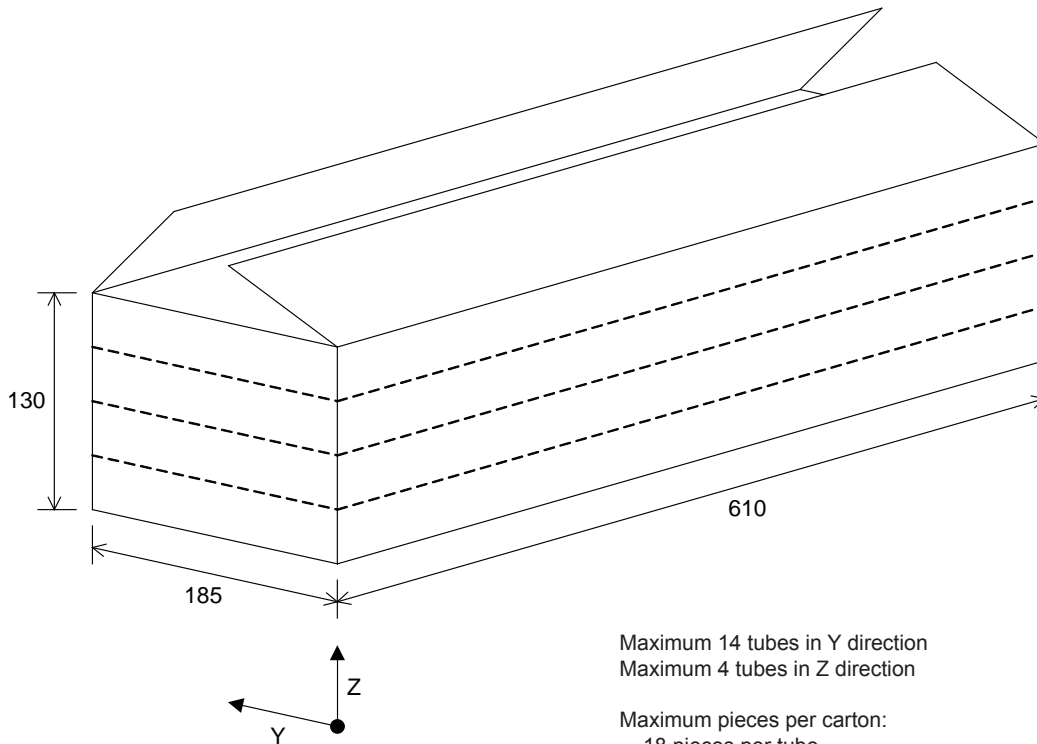
Packing Specification

Leadform 2451

Dimensions in millimeters



Tube material: PVC
Maximum 18 pieces per tube
(pins aligned along X direction)
Rubber plug each end



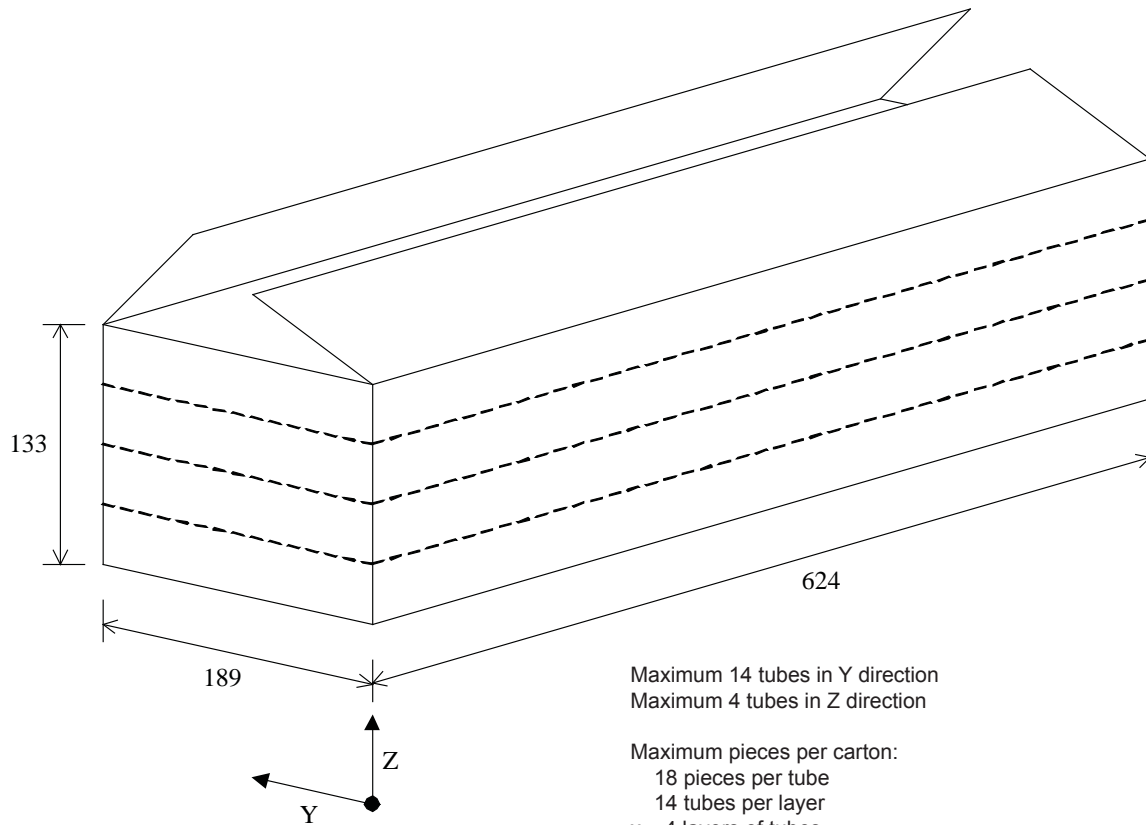
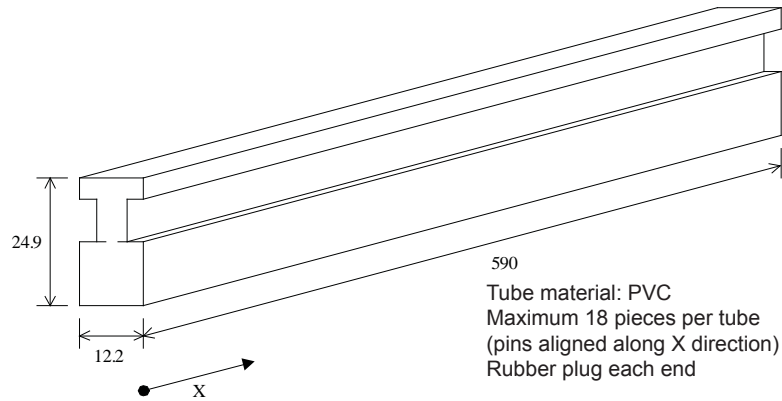
Maximum 14 tubes in Y direction
Maximum 4 tubes in Z direction

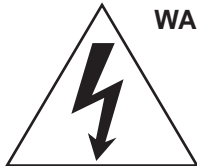
Maximum pieces per carton:
18 pieces per tube
15 tubes per layer
x 4 layers of tubes
1080 pieces per carton

Packing Specification

Leadforms 2452

Dimensions in millimeters





WARNING — These devices are designed to be operated at lethal voltages and energy levels. Circuit designs that embody these components must conform with applicable safety requirements. Precautions must be taken to prevent accidental contact with power-line potentials. Do not connect grounded test equipment.

The use of an isolation transformer is recommended during circuit development and breadboarding.

Because reliability can be affected adversely by improper storage environments and handling methods, please observe the following cautions.

Cautions for Storage

- Ensure that storage conditions comply with the standard temperature (5°C to 35°C) and the standard relative humidity (around 40 to 75%); avoid storage locations that experience extreme changes in temperature or humidity.
- Avoid locations where dust or harmful gases are present and avoid direct sunlight.
- Reinspect for rust on leads and solderability of products that have been stored for a long time.

Cautions for Testing and Handling

When tests are carried out during inspection testing and other standard test periods, protect the products from power surges from the testing device, shorts between adjacent products, and shorts to the heatsink.

Remarks About Using Silicone Grease with a Heatsink

- When silicone grease is used in mounting this product on a heatsink, it shall be applied evenly and thinly. If more silicone grease than required is applied, it may produce stress.
- Volatile-type silicone greases may permeate the product and produce cracks after long periods of time, resulting in reduced heat radiation effect, and possibly shortening the lifetime of the product.
- Our recommended silicone greases for heat radiation purposes, which will not cause any adverse effect on the product life, are indicated below:

Type	Suppliers
G746	Shin-Etsu Chemical Co., Ltd.
YG6260	Momentive Performance Materials, Inc.
SC102	Dow Corning Toray Silicone Co., Ltd.

Soldering

- When soldering the products, please be sure to minimize the working time, within the following limits:
260±5°C 10 s
380±10°C 5 s
- Soldering iron should be at a distance of at least 1.5 mm from the body of the products

Electrostatic Discharge

- When handling the products, operator must be grounded. Grounded wrist straps worn should have at least 1 MΩ of resistance to ground to prevent shock hazard.
- Workbenches where the products are handled should be grounded and be provided with conductive table and floor mats.
- When using measuring equipment such as a curve tracer, the equipment should be grounded.
- When soldering the products, the head of soldering irons or the solder bath must be grounded in order to prevent leak voltages generated by them from being applied to the products.
- The products should always be stored and transported in our shipping containers or conductive containers, or be wrapped in aluminum foil.

The products described herein are manufactured in Japan by Sanken Electric Co., Ltd. for sale by Allegro MicroSystems, Inc.

Sanken and Allegro reserve the right to make, from time to time, such departures from the detail specifications as may be required to permit improvements in the performance, reliability, or manufacturability of its products. Therefore, the user is cautioned to verify that the information in this publication is current before placing any order.

When using the products described herein, the applicability and suitability of such products for the intended purpose shall be reviewed at the users responsibility.

Although Sanken undertakes to enhance the quality and reliability of its products, the occurrence of failure and defect of semiconductor products at a certain rate is inevitable.

Users of Sanken products are requested to take, at their own risk, preventative measures including safety design of the equipment or systems against any possible injury, death, fires or damages to society due to device failure or malfunction.

Sanken products listed in this publication are designed and intended for use as components in general-purpose electronic equipment or apparatus (home appliances, office equipment, telecommunication equipment, measuring equipment, etc.). Their use in any application requiring radiation hardness assurance (e.g., aerospace equipment) is not supported.

When considering the use of Sanken products in applications where higher reliability is required (transportation equipment and its control systems or equipment, fire- or burglar-alarm systems, various safety devices, etc.), contact a company sales representative to discuss and obtain written confirmation of your specifications.

The use of Sanken products without the written consent of Sanken in applications where extremely high reliability is required (aerospace equipment, nuclear power-control stations, life-support systems, etc.) is strictly prohibited.

The information included herein is believed to be accurate and reliable. Application and operation examples described in this publication are given for reference only and Sanken and Allegro assume no responsibility for any infringement of industrial property rights, intellectual property rights, or any other rights of Sanken or Allegro or any third party that may result from its use.

Worldwide ContactsAsia-Pacific**China****Sanken Electric Hong Kong Co., Ltd.**

Suite 1026, Ocean Centre
Canton Road, Tsimshatsui
Kowloon, Hong Kong
Tel: 852-2735-5262, Fax: 852-2735-5494

Sanken Electric (Shanghai) Co., Ltd.

Room 3202, Maxdo Centre
Xingyi Road 8, Changning District
Shanghai, China
Tel: 86-21-5208-1177, Fax: 86-21-5208-1757

Taiwan Sanken Electric Co., Ltd.

Room 1801, 18th Floor
88 Jung Shiau East Road, Sec. 2
Taipei 100, Taiwan R.O.C.
Tel: 886-2-2356-8161, Fax: 886-2-2356-8261

Japan**Sanken Electric Co., Ltd.
Overseas Sales Headquarters**

Metropolitan Plaza Building
1-11-1 Nishi-Ikebukuro, Toshima-ku
Tokyo 171-0021, Japan
Tel: 81-3-3986-6164, Fax: 81-3-3986-8637

Korea**Sanken Electric Korea Co., Ltd.**

Samsung Life Yeouido Building 16F
23-10, Yeouido-Dong, Yeongdeungpo-gu
Seoul 150-734, Korea
Tel: 82-2-714-3700, Fax: 82-2-3272-2145

Singapore**Sanken Electric Singapore Pte. Ltd.**

150 Beach Road, #14-03 The Gateway West
Singapore 189720
Tel: 65-6291-4755, Fax: 65-6297-1744

Europe**Sanken Power Systems (UK) Limited**

Pencoed Technology Park
Pencoed, Bridgend CF35 5HY, United Kingdom
Tel: 44-1656-869-100, Fax: 44-1656-869-162

North America**United States****Allegro MicroSystems, Inc.**

115 Northeast Cutoff
Worcester, Massachusetts 01606, U.S.A.
Tel: 1-508-853-5000, Fax: 1-508-853-7895

Allegro MicroSystems, Inc.

14 Hughes Street, Suite B105
Irvine, California 92618, U.S.A.
Tel: 1-949-460-2003, Fax: 1-949-460-7837